PHOTOCOUPLER

Part Number: KB817-B

GENERAL PURPOSE
HIGH ISOLATION VOLTAGE
SINGLE TRANSISTOR TYPE
PHOTOCOUPLER SERIES

FEATURES

- 1.Lead forming (gull wing) type, for surface mounting.
- 2. High isolation voltage between input and output (Viso=5000 Vrms).
- 3.Compact dual-in-line package

KB817-B:1-channel type

- 4.Recognized by UL and CUL, file NO.E225308.
- 5. Approved by VDE 0884 Teil2(NO:40006364)

(Creepage distance between input and output:7mm or more).

- 6. Moisture Sensitivity Level: Level 4.
- 7.RoHS Compliant.

DESCRIPTION

- 1.The KB817-B (1-channel) is optically coupled isolators containing a GaAS light emitting diode and an NPN silicon phototransistor.
- 2. The lead pitch is 2.54mm.
- 3. Solid insulation thickness between emitting diode and output phototransistor:>=0.6mm.

APPLICATIONS

- 1.Computer terminals.
- 2.Registers,copiers,automatic vending machines.
- 3. System appliances, measuring instruments.
- 4. Programmable logic controller.
- 5. Signal transmission between circuits of different potentials and impedances.





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 REV NO: V.16
 DATE: APR/26/2012
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 APPROVED: WYNEC
 CHECKED: Tracy Deng
 DRAWN : C.H.HAN
 ERP: 1205000007

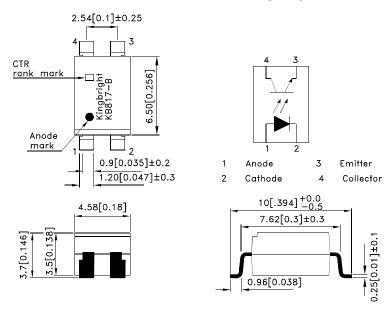
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*PACKAGE DIMENSIONS (UNIT:mm)

Lead Bending Type

TOLERANCE: ±0.5[±0.02] UNLESS OTHERWISE NOTED.



*Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I _F	50	mA
	Reverse voltage	V_R	6	V
	Power dissipation	Р	70	mW
Output	Collector-emitter voltage	V _{CEO}	35	V
	Emitter-collector voltage	V _{ECO}	6	V
	Collector current	I _c	50	mA
	Collector power dissipation	P _c	150	mW
Total power dissipation		Ptot	200	mW
¹¹ Isolation voltage		Viso	5000	Vrms
Operating temperature		Topr	-30~+100	°C
Storage temperature		Tstg	-55~+125	°C
*2Soldering temperature		Tsol	260	°C

^{*1 40} to 60% RH,AC for 1 minute.

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^{*2} For 10 seconds.





Part Number: KB817-B

*Electro-optical Characteristics

Parameter		Symbol	Conditions	Min.	Тур.	Max.	Unit	
Input	Forward voltage		VF	IF=20mA		1.2	1.4	V
	Peak forward voltage		VFM	Iғм=0.5A			3.0	V
	Reverse current		l R	V _R =4V			10	μА
Output	Collector dark cur	rent	ICEO	Vce=20V,Ir=0mA		_	10 ⁻⁷	Α
	*1Current transfer	ratio	CTR	IF=5mA,VcE=5V	50		600	%
Transfer charact-eristics	Collector-emitter s	aturation voltage	VCE(sat)	IF=20mA, Ic=1mA		0.1	0.2	V
	Cut-off frequency		fc	VcE=5V, lc=2mA RL=100Ω,-3dB		80		KHz
	Response time Rise time Fall time	Rise time	tr	VcE=2V, Ic=2mA		4	18	μS
		tf	RL=100Ω		3	18	μS	

^{*1} Classification table of current transfer ratio is shown below.

$$CTR = \frac{Ic}{I_F} X 100\%$$

Model No.	Rank mark	CTR(%)	
KB817L-B	L	50 to 100	
KB817A-B	А	80 to 160	
KB817B-B	В	130 to 260	
KB817C-B	С	200 to 400	
KB817D-B	D	300 to 600	
KB817AB-B	A or B	80 to 260	
KB817BC-B	B or C	130 to 400	
KB817CD-B	C or D	200 to 600	
KB817AC-B	A,B or C	80 to 400	
KB817BD-B	B,C or D	130 to 600	
KB817AD-B	A,B,C or D	80 to 600	
KB817-B	L,A,B,C,D or No mark	50 to 600	

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Part Number: KB817-B

Fig. 1 Current Transfer Ratio vs. Forward Current

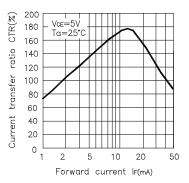


Fig. 2 Forward Current vs. Forward voltage

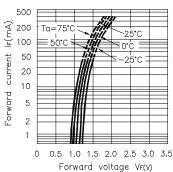


Fig. 3 Collector Current vs.
Collector-emitter Voltage

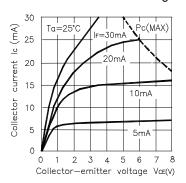


Fig. 4 Relative Current Transfer Ratio vs. Ambient Temperature

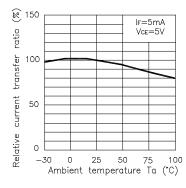


Fig. 5 Collector-emitter Saturation Voltage vs. Ambient Temperature

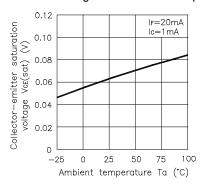
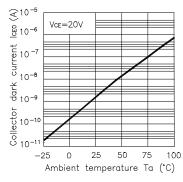


Fig. 6 Collector Dark Current vs.
Ambient Temperature



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Fig. 7 Forward Current vs.

Ambient Temperature

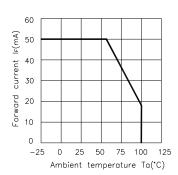


Fig. 9 Response Time vs.
Load Resistance

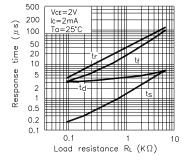


Fig. 10 Frequency Response

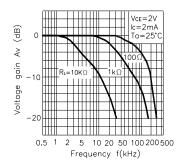


Fig. 11 Collector-emitter Saturation Voltage vs. Forward Current

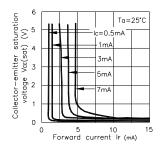
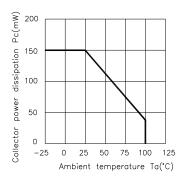
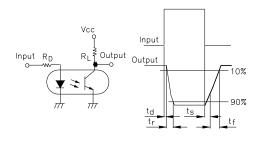


Fig. 8 Collector Power Dissipation vs.
Ambient Temperature

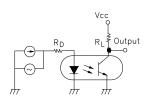
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Test Circuit for Response Time



Test Circuit for Frequency Response



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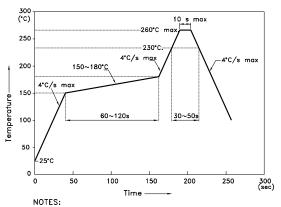
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*NOTES ON HANDLING

1. Cautions regarding noise

Be aware that power is suddenly into the componment any surge current may cause damage happen, even if the voltage is within the absolute maximum ratings.

Reflow Soldering Profile For Lead-free SMT Process.



- 1.We recommend the reflow temperature 245°C(+/-5°C). The maximum soldering temperature should be limited to 260°C.
 2.Don't cause stress to the epoxy resin while it is exposed.
 - to high temperature.

 3.Number of reflow process shall be 2 times or less.

CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested.

GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them.

RESTRICTIONS ON PRODUCT USE

- The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version. Not all devices / types available in every country.
- We are mention about our product quality stablity, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing KINGBRIGHT products, to observe standards of safety, and to a avoid situations in which a malfunction or failure of a KINGBRIGHT product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that KINGBRIGHT products are used within specified operating ranges as set forth in the most recent products specifications.

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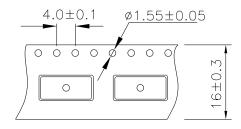
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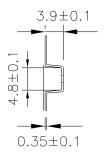
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Outline and Dimension (Tape) (Unit :mm)

KB817-B

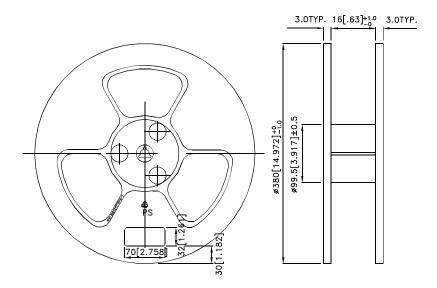




Tape Direction



Outline and Dimension(Reel)



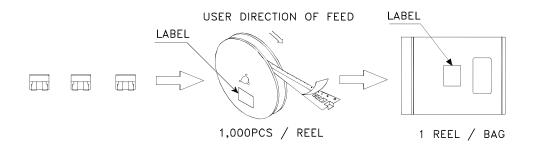
Packing:1000pcs/reel

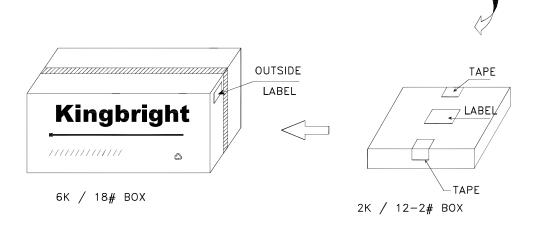
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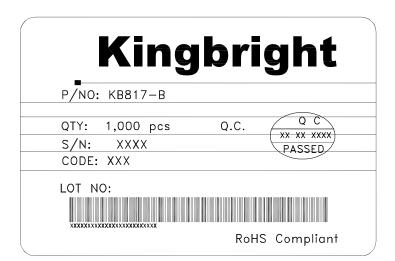
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PACKING & LABEL SPECIFICATIONS







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